

GENERAL DESCRIPTION

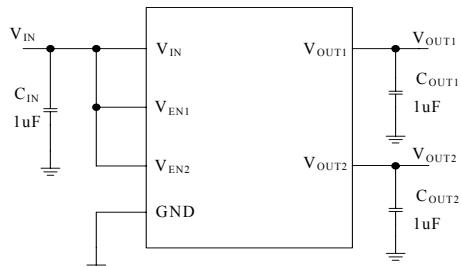
The PT5127 is a dual channel low-dropout voltage regulator designed for portable and wireless applications that require high PSRR, low quiescent current and excellent line and load transient response. The PT5127 is stable with a small 1 μ F ceramic capacitor on the output. With its better than 75dB PSRR at 1kHz, the PT5127 is ideal for battery powered systems for delivering low dropout voltage and low quiescent current.

This device can be used for mobile phones and similar battery powered wireless applications. It provides up to 200mA at each channel, from a 2.0V to 5.5V input. The PT5127 consumes less than 0.1 μ A in shutdown mode. The PT5127 is available in 6 pin SOT23 package. The output voltage is available at 1.8V, 2.5V, 2.8V, 3.3V and 1.5V/3.0V.

FEATURES

- 2.0V to 5.5V input range
- 200mA guaranteed output current (each channel)
- High PSRR: 75dB at 1KHz (each channel)
- 180mV maximum low dropout voltage with 100mA load (each channel)
- Low quiescent current: 50 μ A (Typ.)
- Current Limiting and Thermal Protection
- -40°C to +85°C junction temperature for operation

TYPICAL APPLICATIONS

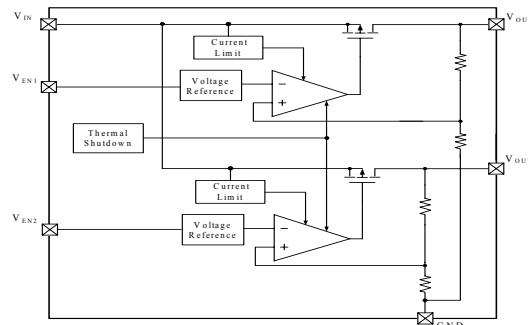


*Note:
C_{OUT1}, C_{OUT2}: Recommended ceramic capacitor

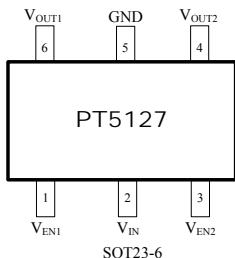
APPLICATIONS

- CDMA/GSM mobile phone
- Laptop computers
- PDAs/MP3
- WLAN and bluetooth appliances
- Cordless telephones
- Battery powered portable devices

BLOCK DIAGRAM



PIN ASSIGNMENT



ABSOLUTE MAXIMUM RATINGS

PARAMETER	VALUE	UNIT
V _{IN} Range	-0.3~6.0V	V
V _{OUT1} , V _{OUT2} Range	-0.3~(V _{IN} +0.3)< 6.0V	V
V _{EN1} , V _{EN2} Range	-0.3~6.0V	V
Maximum Power Dissipation	360	mW
Junction Temp.	150	°C
Storage Temp.	-65~150	°C
Lead Temp.	235	°C
ESD Rating, HBM	2	kV

PIN DESCRIPTIONS

Symbol	SOT23-6	Description
V _{IN}	2	Input of LDO
GND	5	Ground
V _{EN1}	1	LDO1 Enable Input Logic, Enable High
V _{EN2}	3	LDO2 Enable Input Logic, Enable High
V _{OUT1}	6	Output of LDO1
V _{OUT2}	4	Output of LDO2

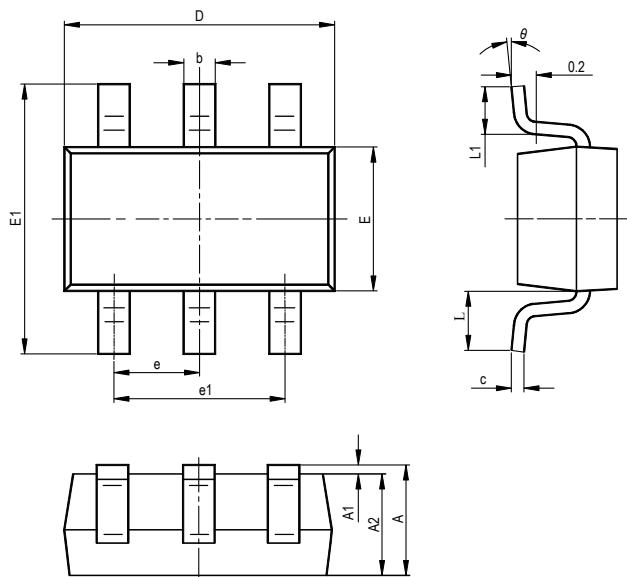
OPERATING RANGE

PARAMETER	VALUE	UNIT
V _{IN} Range	-0.3~5.5V	V
V _{EN1} , V _{EN2} Range	-0.3~(V _{IN} +0.3)<5.5V	V
Thermal Resistance, θ_{JA}	220	°C/W
Maximum Power Dissipation	250	mW
Operation Temp.	-40~85	°C

ELECTRICAL CHARACTERISTICS

Unless otherwise specified: $V_{IN} = V_{OUT(nom)} + 1.0V$, $V_{EN} = V_{IN}$, $C_{IN} = 1\mu F$, $I_{OUT} = 30mA$, $C_{OUT} = 1\mu F$, $T_A = +25^\circ C$.								
Symbol	Parameter	Conditions			Typ.	Min.	Max.	Unit
ΔV_{OUT}	Output Voltage Error	$I_{OUT} = 30mA$				-2	2	% V_{OUT}
	Line Regulation Error	$I_{OUT} = 30mA$, $V_{IN} = (V_{OUT(nom)} + 0.5V)$ to $5.5V$			0.01	-0.1	0.1	%/ V
	Load Regulation Error	$I_{OUT} = 1mA$ to $150mA$			15		50	mV
I_{OUTMAX}	One output Maximum Output Current					200		mA
PSRR	Power Supply Rejection Ratio	$V_{IN} = V_{OUT(nom)} + 1.0V$	$f = 1kHz$	$I_{OUT} = 50mA$	75			dB
				$I_{OUT} = 150mA$	75			
			$f = 10kHz$	$I_{OUT} = 50mA$	70			
				$I_{OUT} = 150mA$	65			
I_Q	Quiescent Current	$I_{OUT} = 0mA$, $V_{OUT} = 2.5V$			50		100	uA
		$V_{EN} = 0V$			0.1		1.0	
V_{DIFF}	Dropout Voltage	$I_{OUT} = 50mA$			50		90	mV
		$I_{OUT} = 100mA$			100		180	
I_{SC}	One Output Short Current Limit	One of the Outputs Grounded			500			mA
T_{ON}	Turn-On Time				150			us
V_{IL}	Maximum Low Input Level at V_{EN1} and V_{EN2}	$V_{IN} = 2.5$ to 5.5					0.4	V
V_{IH}	Minimum High Input Level at V_{EN1} and V_{EN2}	$V_{IN} = 2.5$ to 5.5				1.4		V
TSD	Thermal Shutdown Temperature				160			°C
	Thermal Shutdown Hysteresis				20			°C
$\Delta V_{OUT}/V_{OUT}$	V_{OUT} Temperature Characteristics	Temperature = -40 to $125^\circ C$			100			ppm/°C

PACKAG INFORMATION



Symbol	Millimeters		Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.400	0.012	0.016
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.700REF		0.028REF	
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°